

MECHANICAL and PACKAGING

• CASE: Hermetically sealed, kovar base, nickel cap.

table)

- TERMINALS: Solder dip (Sn63/Pb37), RoHS compliant matte-tin plating available on commercial grade only.
- MARKING: Part number, date code, manufacturer's ID and serial number
- WEIGHT: Approximately 1.2 grams
- See <u>package dimensions</u> on last page.

JAN 2N6350 (e3) Reliability Level JAN = JAN Level JANTX = JANTX Level JANTXV = JANTXV Level Blank = Commercial JEDEC type number (see Electrical Characteristics

SYMBOLS & DEFINITIONS				
Symbol	Definition			
I _B	Base current: The value of the dc current into the base terminal.			
Ic	Collector current: The value of the dc current into the collector terminal.			
I _E	Emitter current: The value of the dc current into the emitter terminal.			
T _C	Case temperature: The temperature measured at a specified location on the case of a device.			
V _{CB}	Collector-base voltage: The dc voltage between the collector and the base.			
V _{CBO}	Collector-base voltage, base open: The voltage between the collector and base terminals when the emitter terminal is open-circuited.			
V _{CC}	Collector-supply voltage: The supply voltage applied to a circuit connected to the collector.			
V _{CEO}	Collector-emitter voltage, base open: The voltage between the collector and the emitter terminals when the base terminal is open-circuited.			
V _{CE}	Collector-emitter voltage: The dc voltage between the collector and the emitter.			
V _{EB}	Emitter-base voltage: The dc voltage between the emitter and the base.			
V _{EBO}	Emitter-base voltage, collector open: The voltage between the emitter and base terminals with the collector terminal open-circuited.			



ELECTRICAL CHARACTERISTICS @ T_A = +25 °C unless otherwise noted

Characteristics		Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage $I_C = 25 \text{ mA}$, $R_{B1E} = 2.2 \text{ k}\Omega$, $R_{B2E} = 100 \Omega$	2N6350 2N6351	V _{(BR)CEO}	80 150		V
Collector-Emitter Breakdown Voltage $I_E = 12$ mA, base 1 open $I_E = 12$ mA, base 2 open		$V_{(BR)EBO}$	6.0 12		V
Collector-Emitter Cutoff Current $V_{CE} = 80 \text{ V}, V_{EB1} = 2 \text{ V}, R_{B2E} = 100 \Omega$ $V_{CE} = 150 \text{ V}, V_{EB1} = 2 \text{ V}, R_{B2E} = 100 \Omega$	2N6350 2N6351	I _{CEX}		1.0	μΑ
ON CHARACTERISTICS					
Forward-Current Transfer Ratio $I_C = 1.0 \text{ A}, V_{CE} = 5.0 \text{ V}, R_{B2E} = 1 \text{ k}\Omega$	2N6350 2N6351		2,000 1,000		
$I_C = 5.0 \text{ A}, V_{CE} = 5.0 \text{ V}, R_{B2E} = 100 \Omega$	2N6350 2N6351	hFE	2,000 1,000	10,000 10,000	
$I_C = 10.0 \text{ A}, V_{CE} = 5.0 \text{ V}, R_{B2E} = 100 \Omega$	2N6350 2N6351		400 200		
Collector-Emitter Saturation Voltage $I_C = 5.0 \text{ A}, I_B = 5 \text{ mA}, R_{B2E} = 100 \Omega$ $I_C = 5.0 \text{ A}, I_B = 10 \text{ mA}, R_{B2E} = 100 \Omega$		$V_{\text{CE(sat)}}$		1.5 2.5	٧
Base-Emitter Voltage Non-saturated $V_{CE} = 5.0 \text{ V}, I_C = 5.0 \text{ A}, R_{B2E} = 100 \Omega$		V_{BE}		2.5	V
DYNAMIC CHARACTERISTICS					
Magnitude of Common Emitter Small-Signal S	Short-Circuit				
Forward Current Transfer Ratio $I_C = 1.0 \text{ A}, V_{CE} = 10.0 \text{ V}, f = 10 \text{ MHz}, R_{B2E} =$	hfe	5	25		
Output Capacitance V _{CB} = 10 V, 100 kHz ≤ f ≤ 1 MHz, base 2 ope	en	Cobo		120	pF



ELECTRICAL CHARACTERISTICS @ T_C = 25 °C unless otherwise noted. (continued)

SWITCHING CHARACTERISTICS

Turn-On Time $V_{CC} = 30 \text{ V}, I_C = 5.0 \text{ A}$	t _{on}	0.5	μS
Turn-Off Time $V_{CC} = 30 \text{ V}, I_C = 5.0 \text{ A}$	t _{off}	1.2	μS

SAFE OPERATING AREA (See Figures 1 and 2 and MIL-STD-750, Test Method 3053)

DC Tests $T_C = +100$ °C, $t \ge 1$ second, 1 Cycle; $t_r + t_f = 10$ μs, $R_{B2E} = 100$ Ω Test 1 $V_{CE} = 1.5$ V, $I_C = 3.3$ A Test 2 $V_{CE} = 30$ V, $I_C = 167$ mA Test 3 $V_{CE} = 80$ V, $I_C = 35$ mA (2N6350)

Test 4 $V_{CE} = 150 \text{ V}, I_{C} = 13 \text{ mA } (2N6351)$



SAFE OPERATING AREA

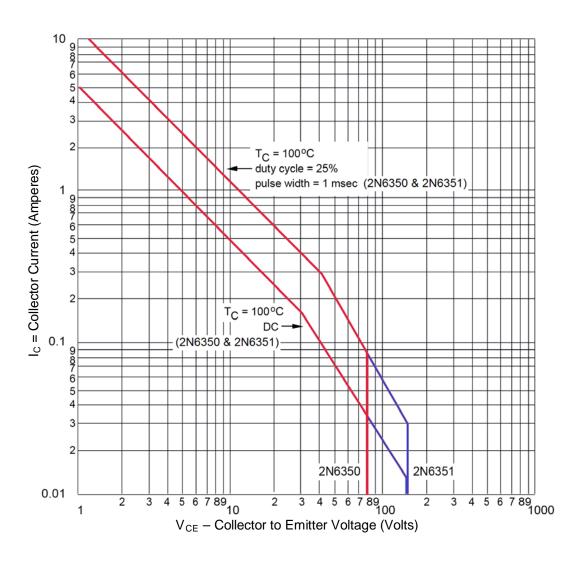


FIGURE 1

Maximum Safe Operating Area



SAFE OPERATING AREA (continued)

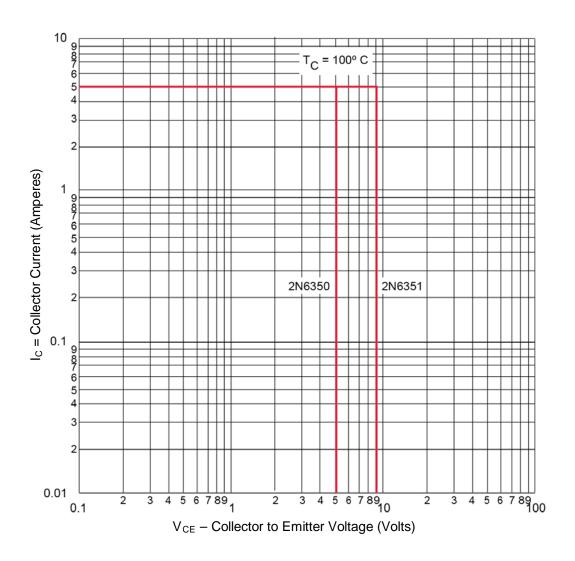
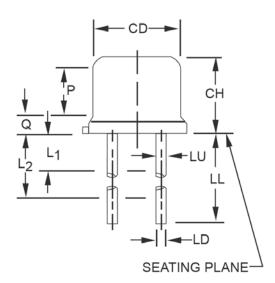
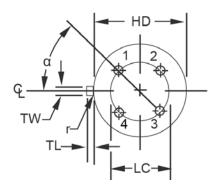


FIGURE 2
Safe Operating Area For Switching Between Saturation And Cutoff (unclamped inductive load)



PACKAGE DIMENSIONS





	Dimensions				
Symbol	Inches		Millimeters		Notes
	Min	Max	Min	Max	
CD	0.305	0.335	7.75	8.51	3
СН	0.240	0.260	6.10	6.60	
HD	0.335	0.370	8.51	9.40	
LC	0.200 TP		00 TP 5.08 TP		4
LD	0.016	0.021	0.41	0.53	5, 6
LL	1.500	1.750	38.10	44.45	5, 6
LU	0.016	0.019	0.41	0.48	5, 6
L ₁	-	0.050	-	1.27	5, 6
L ₂	0.250	-	6.35	-	5, 6
Q	-	0.050	-	1.27	9
TL	0.029	0.045	0.74	1.14	7
TW	0.028	0.034	0.71	0.86	8
r	-	0.010	-	0.25	10
α	45° TP		45°	TP	4
Р	0.100	-	2.54	-	3

NOTES:

- 1. Dimensions are in inches. Millimeters are given for information only.
- 2. Internal resistance (typically 750 ohms). This resistor is optional.
- 3. Dimension CD shall not vary more than 0.010 inch (0.25 mm) in zone P. This zone is controlled for automatic handling.
- 4. Leads at gauge plane 0.054 +0.001 -0.000 inch (1.37 +0.03 -0.00 mm) below seating plane shall be within 0.007 inch (0.18 mm) radius of true position (TP) at maximum material condition (MMC) relative to tab at MMC. The device may be measured by direct methods.
- 5. Dimension LU applies between dimension L1 and dimension L2. Dimension LD applies between L2 and LL minimum. Diameter is uncontrolled in dimension L1 and beyond dimension LL minimum.
- 6. All terminals.
- 7. Dimension TL measured from maximum HD.
- 8. Beyond r (radius) maximum, dimension TW shall be held for a minimum length of 0.011 inch (0.28 mm).
- 9. Outline in this zone is not controlled.
- 10. The radius (dimension r) applies to both inside corners of the tab.
- 11. Terminal designation is as follows: 1 emitter, 2 base (B2), 3 base (B1), 4 collector. The collector shall be connected to the case.
- 12. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.

See schematic on next page



SCHEMATIC

